HD31279
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Class AB linear GaN design
Instantaneous wide bandwidth
Suitable for all single channel modulation standards
Small form factor & light weight
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	2.0 - 4.0 GHz	
Power Output @ Psat	170 Watt Min	CW
Power Output @ P1dB GCP	80 Watt Typ	
Power Gain	53 dB Min	
Power Gain Flatness	3.0 dB p-p Max	Constant input power
Input / Output Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	44dBm/Tone, Δ = 1 MHz
Harmonics	-20 dBc Typ	At rated Pout
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	32 VDC Nom	
Current Consumption	40 Amp Max	
Max Input Power	+8 dBm Max	<10 Sec without damage
Load VSWR Protection	∞ : 1	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +65 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	270 x 200 x 27mm	Excluding connectors
Weight	-	
RF Connectors In/Out	SMA / Type-N female	
DC Power / Interface Connector	Hybrid 9-Pin D-Sub	9W4
Cooling	External Heatsink	Forced air required

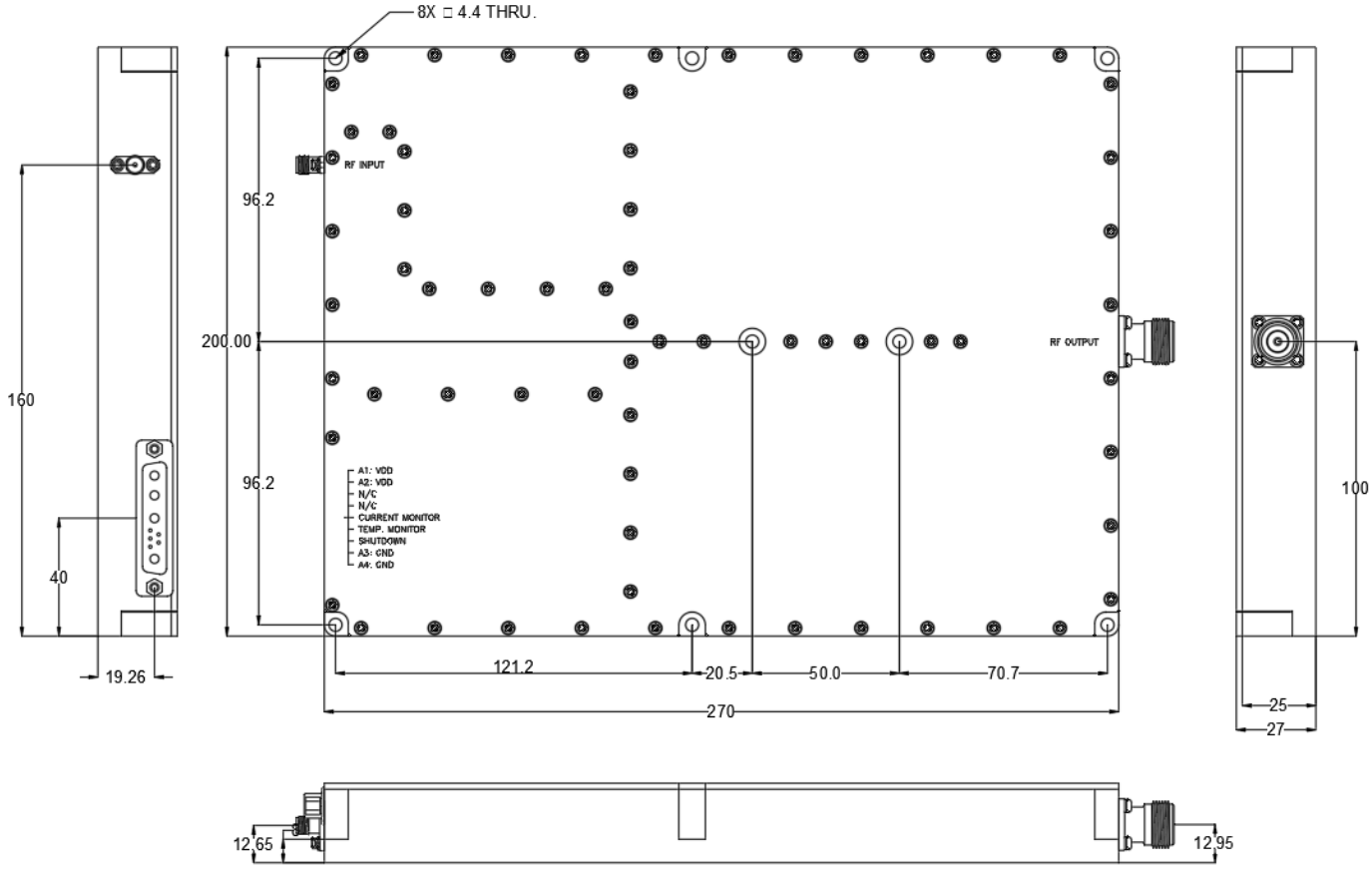
332C Dante Ct. Holbrook, NY 11741 Phone: 631-588-3877 Fax: 631-648-0518
www.rfamplifiers.com www.rfcomp.com sales@hdcom.com

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D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	OPTION 101 - Forward power detect
2	VVA	OPTION 103 - Variable Voltage Attenuator
3	CURRENT SENSOR	I_D@20mV/100mA Typ
4	TEMP SENSOR	V_T@10mV/°C + 500mV Typ
5	SHUTDOWN	TTL
A1, A2	VDD	32VDC
A3, A4	GND	Ground

OUTLINE DRAWING



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